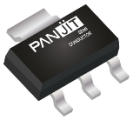
PJW4P06A-AU

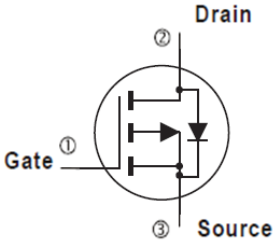
60V P-Channel Enhancement Mode MOSFET

Voltage	-60 V	Current	-4 A

SOT-223



1



Features

- $R_{DS(ON)}$, V_{GS}@-10V, I_D@-4A<110mΩ
- $R_{DS(ON)}$, V_{GS}@-4.5V, I_D@-2A<130mΩ
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-223 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.123grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	-60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current(Note 4)	T_A=25°C	I_D	-4	A
	T_A=70°C		-3.2	A
Pulsed Drain Current(Note 1)		I_{DM}	-16	A
Power Dissipation	T_A=25°C	P_D	3.1	W
	T_A=70°C		2	W
Single Pulse Avalanche Energy(Note 6)		E_{AS}	12.8	mJ
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient(Note 4,5)		$R_{\theta JA}$	40.3	°C/W

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=-250uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=-10V, I_D=-4A	-	87	110	mΩ
		V_{GS}=-4.5V, I_D=-2A	-	110	130	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-60V, V_{GS}=0V	-	-	-1	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Dynamic(Note 7)						
Total Gate Charge	Q_g	V_{DS}=-30V, I_D=-4A, V_{GS}=-10V(Note 2,3)	-	10	-	nC
Gate-Source Charge	Q_{gs}		-	1.6	-	
Gate-Drain Charge	Q_{gd}		-	3	-	
Input Capacitance	Ciss	V_{DS}=-30V, V_{GS}=0V, f=1MHZ	-	785	-	pF
Output Capacitance	Coss		-	175	-	
Reverse Transfer Capacitance	Crss		-	112	-	
Turn-On Delay Time	$td_{(on)}$	V_{DS}=-30V, R_L=30Ω, V_{GS}=-10V, R_G=6.2Ω (Note 2,3)	-	8	-	ns
Turn-On Rise Time	t_r		-	15	-	
Turn-Off Delay Time	$td_{(off)}$		-	43	-	
Turn-Off Fall Time	t_f		-	8.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	-4	A
Diode Forward Voltage	V_{SD}	I_S=-1A, V_{GS}=0V	-	-0.76	-1	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 $inch^2$ with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=16A, V_{DD}=25V, V_{GS}=10V.
7. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

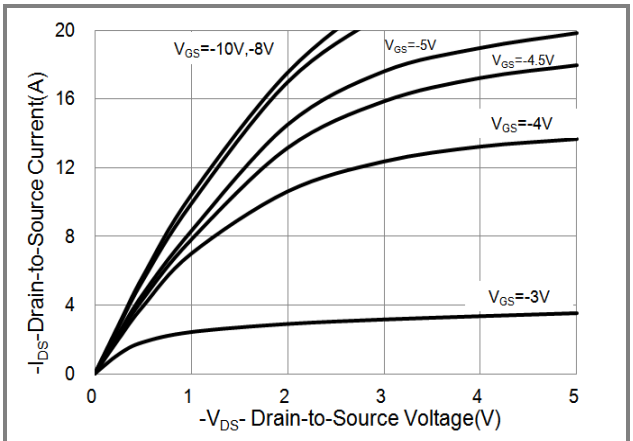

Fig.1 Output Characteristics

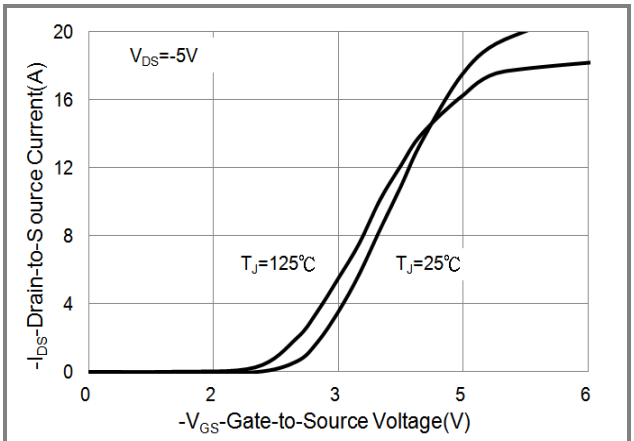

Fig.2 Transfer Characteristics

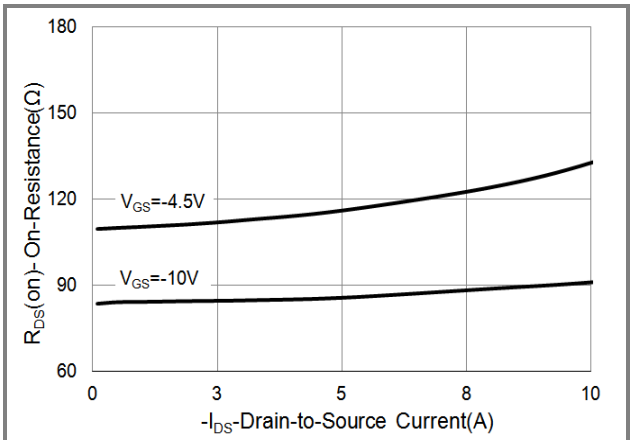

Fig.3 On-Resistance vs. Drain Current

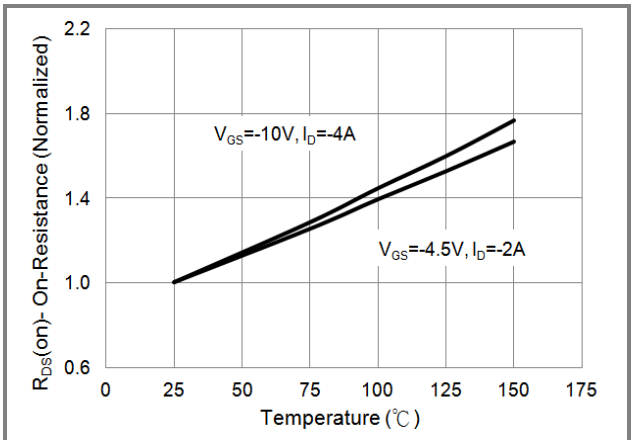

Fig.4 On-Resistance vs. Junction temperature

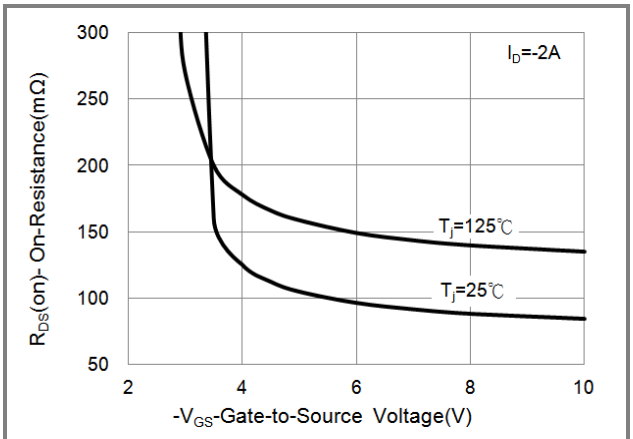

Fig.5 On-Resistance Variation with V_{GS}

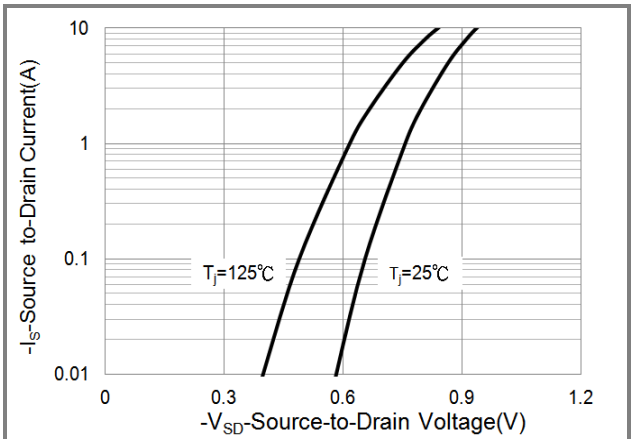

Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

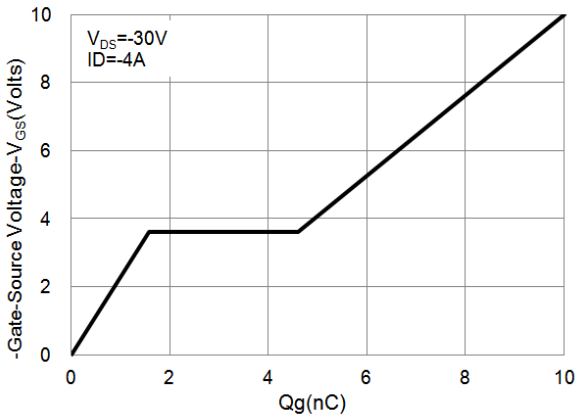

Fig.7 Gate-Charge Characteristics

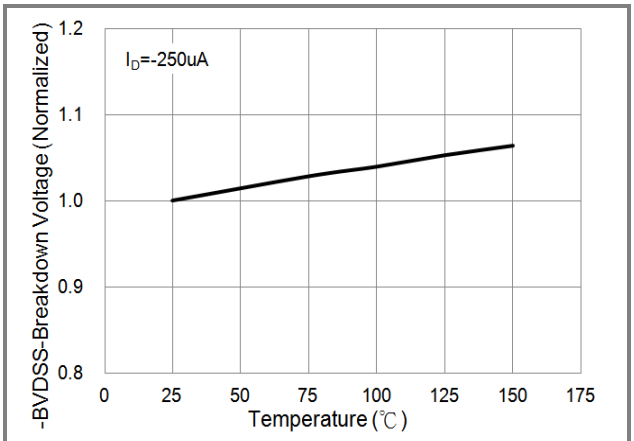

Fig.8 Breakdown Voltage Variation vs. Temperature

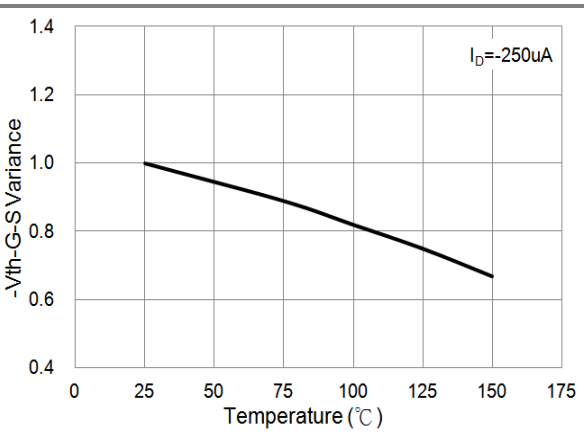

Fig.9 Threshold Voltage Variation with Temperature

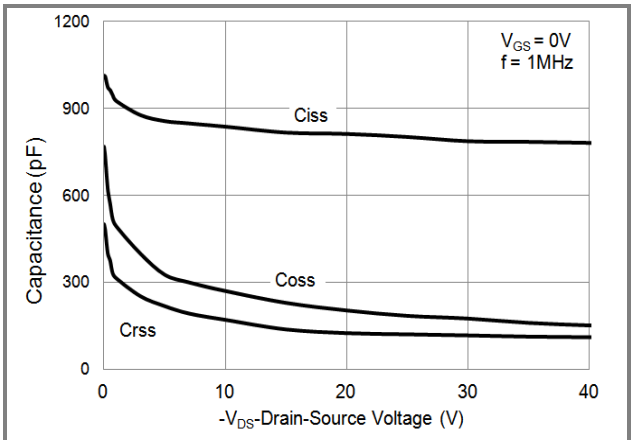

Fig.10 Capacitance vs. Drain-Source Voltage

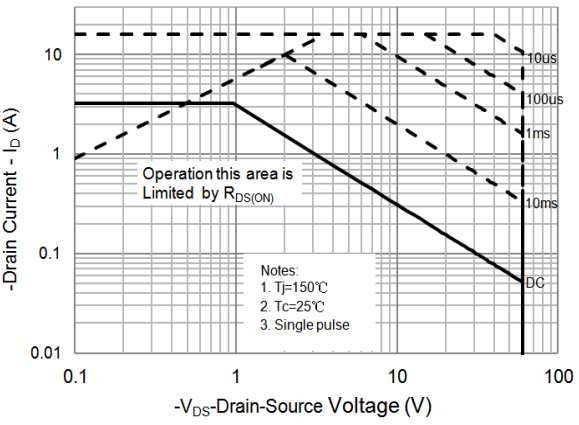

Fig.11 Maximum Safe Operating Area

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TYPICAL CHARACTERISTIC CURVES

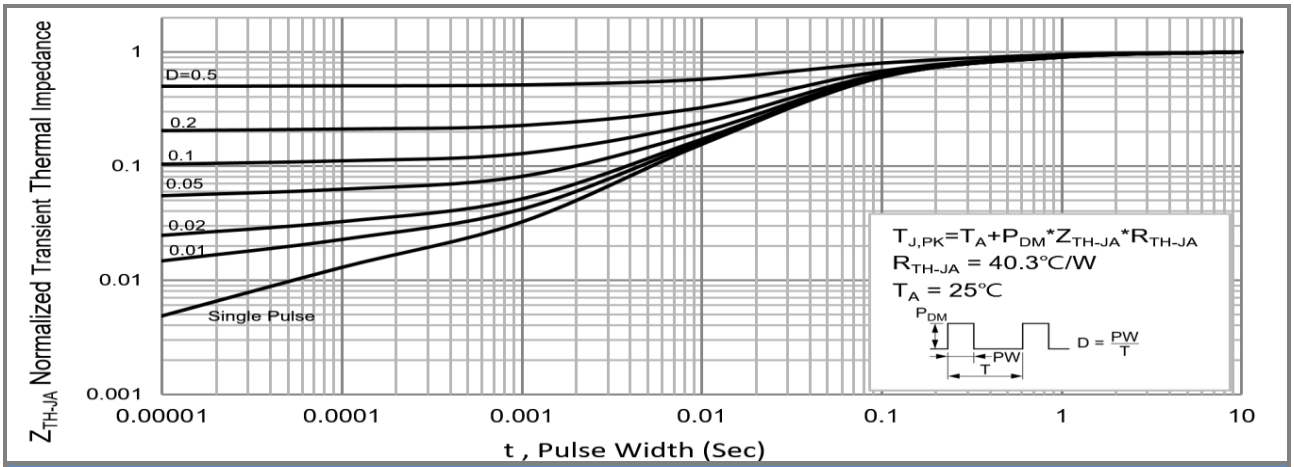

Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

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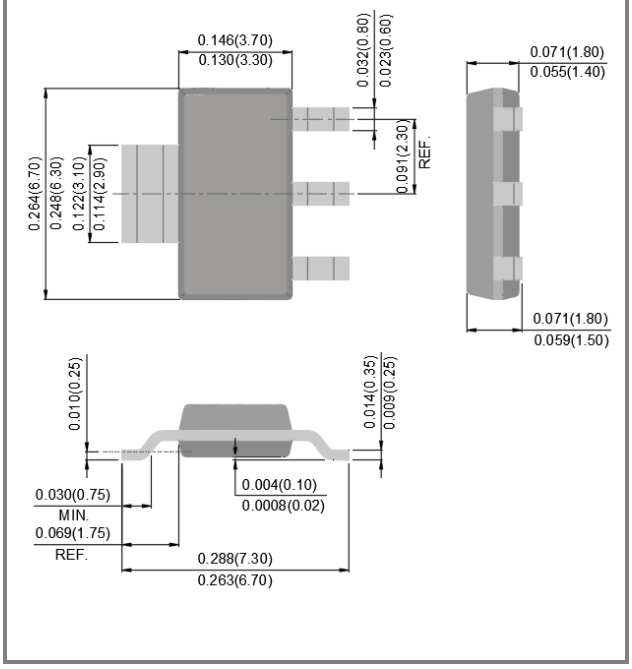
Product and Packing Information

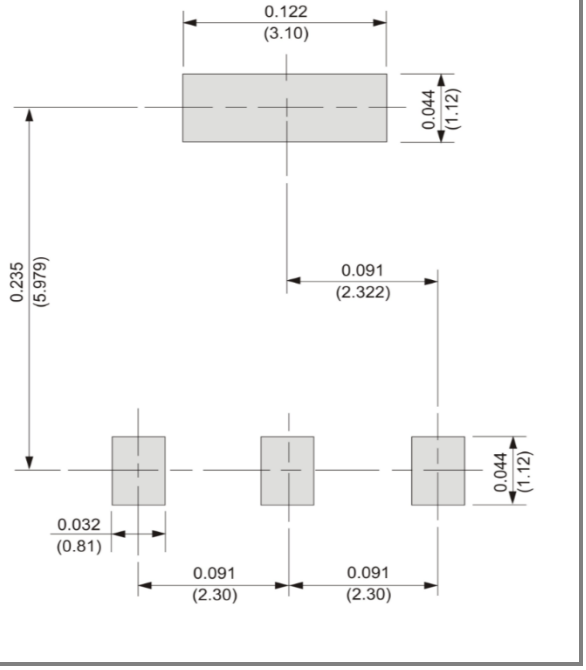
Part No.	Package Type	Packing Type	Marking
PJW4P06A-AU	SOT-223	2.5K pcs / 13” reel	W4P06A

Packaging Information & Mounting Pad Layout

SOT-223 Dimension — Unit: inch(mm)



SOT-223 Pad Layout — Unit: inch(mm)



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